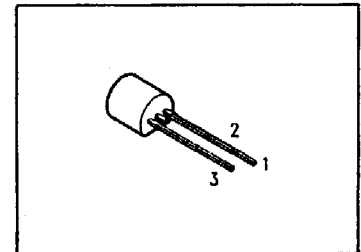


BF 254B

Maximum Ratings

Parameter	Symbol	Values	Unit
Collector-emitter voltage	V_{CE0}	20	V
Collector-base voltage	V_{CB0}	30	
Emitter-base voltage	V_{EB0}	5	
Collector current	I_C	30	mA
Total power dissipation, $T_A \leq 45^\circ\text{C}$	P_{tot}	250	mW
Junction temperature	T_J	150	°C
Storage temperature range	T_{stg}	-65 ... +150	



Pin Configuration			Package
1	2	3	
C	E	B	TO-92

Thermal Resistance

Junction - ambient	R_{thJA}	≤ 420	K/W
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Electrical Characteristics
at $T_A = 25^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

DC Characteristics

DC current gain $I_C = 1\text{ mA}$, $V_{CE} = 10\text{ V}$ BF 254B	h_{FE}	110	-	220	-
Base-emitter voltage $I_C = 1\text{ mA}$, $V_{CE} = 10\text{ V}$	V_{BE}	-	0.68	-	V

AC Characteristics

Transition frequency $I_C = 1\text{ mA}$, $V_{CE} = 10\text{ V}$, $f = 100\text{ MHz}$ BF 254	f_t	-	260	-	MHz
Collector-base capacitance $V_{CE} = 10\text{ V}$, $V_{BE} = 0\text{ V}$, $f = 1\text{ MHz}$	C_{cb}	-	0.6	-	pF
Collector-emitter capacitance $V_{CE} = 10\text{ V}$, $V_{BE} = 0\text{ V}$, $f = 1\text{ MHz}$	C_{ce}	-	0.6	-	
Noise figure $I_C = 1\text{ mA}$, $V_{CE} = 10\text{ V}$ $f = 1\text{ MHz}$, $g_s = 1.5\text{ mS}^{(1)}$ $f = 100\text{ MHz}$, $g_s = 10\text{ mS}^{(1)}$	F	-	1.2	-	dB
		-	3.8	-	

Y parameters, typical values, $I_C = 10\text{ V}$

f MHz		g_{11} mS	b_{11} mS	$ y_{12} $ μS	ϕ_{12} deg.	$ y_{21} $ mS	ϕ_{21} deg.	g_{22} μS	b_{22} μS
Common emitter									
0.45	BF 254	0.3	0.06	1.7	-90	38	0	3.2	3.4
10.7	BF 254	0.4	1.5	41	-90	37	-10	4	8.1

¹⁾ g_s = generator conductance

